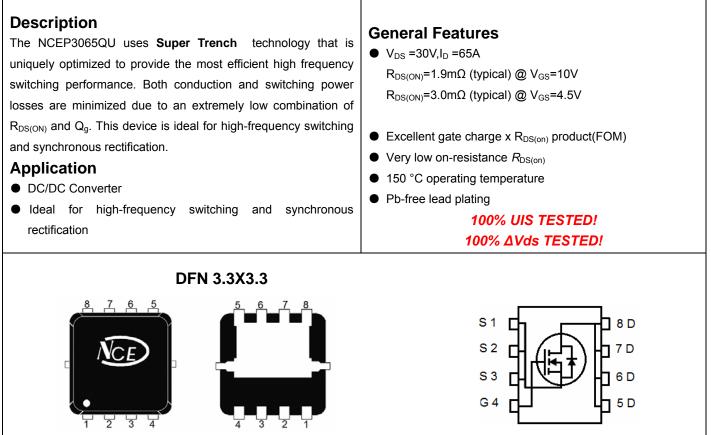


# NCE N-Channel Super Trench Power MOSFET



Top View

Bottom View

#### **Schematic Diagram**

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP3065QU	NCEP3065QU	DFN3.3X3.3-8L	Ø180mm	-	5000

### Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	65	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	45.5	А
Pulsed Drain Current	I <sub>DM</sub>	260	А
Maximum Power Dissipation	PD	55	W
Derating factor		0.44	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	500	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	2.3	°C <b>/W</b>	]
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# Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

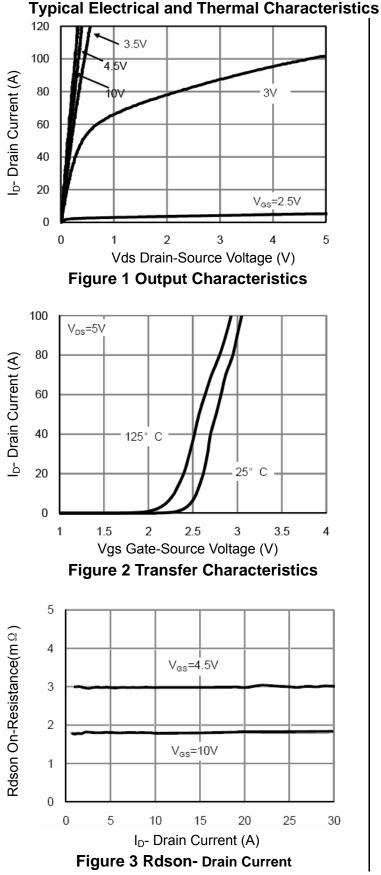
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	-	1	μA
Cata Rady Laakaga Current		$V_{GS}$ =±5V, $V_{DS}$ =0V	-	-	±80	nA
Gate-Body Leakage Current	I <sub>GSS</sub> –	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)	····					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.5	2.0	V
Drain-Source On-State Resistance	P	$V_{GS}$ =10V, I <sub>D</sub> =20A	1.6	1.9	2.3	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	2.5	3.0	3.6	mΩ
Gate resistance	R <sub>G</sub>	F=1.0MHz	-	2.0	-	Ω
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		60	-	S
Dynamic Characteristics (Note4)	····					
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V,	-	2100	2800	PF
Output Capacitance	C <sub>oss</sub>		-	773	1400	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	15.5	30	PF
Switching Characteristics (Note 4)	<b>i</b>					
Turn-on Delay Time	t <sub>d(on)</sub>		-	7.5	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =15V,I <sub>D</sub> =20A	-	4.0	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =1.6Ω	-	37	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	7.5	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =15V,I <sub>D</sub> =20A,	-	34.8	52	nC
Gate-Source Charge	Q <sub>gs</sub>		-	6.2	9.3	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	5.1	7.7	nC
Drain-Source Diode Characteristics	· ·					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	65	А
Reverse Recovery Time	t <sub>rr</sub>	$T_J$ = 25°C, $I_F$ = $I_S$	-	14	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	21	-	nC

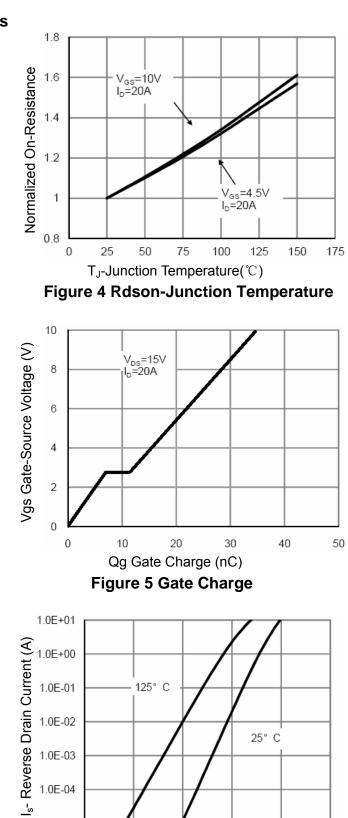
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- Surface Mounted on FR4 Board, t ≤ 10 sec. The value of R<sub>0JA</sub> is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub> =25° C. the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^\circ \! \mathrm{C}$  ,V\_DD=15V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$



# <u>NCEP3065QU</u>





1.0E-05

0.0

0.2

0.4

Vsd Source-Drain Voltage (V) Figure 6 Source- Drain Diode Forward

0.6

0.8

1.0



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# NCEP3065QU

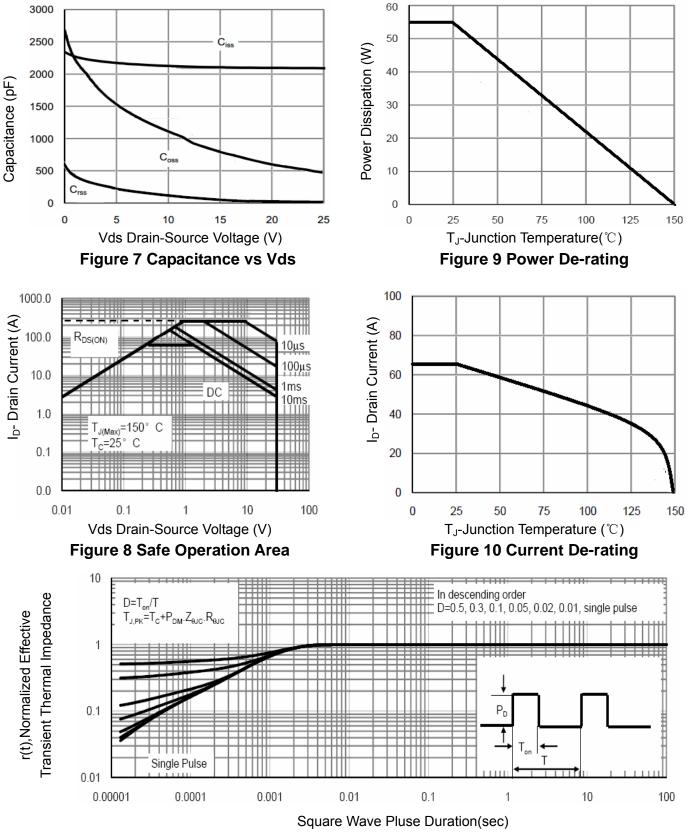
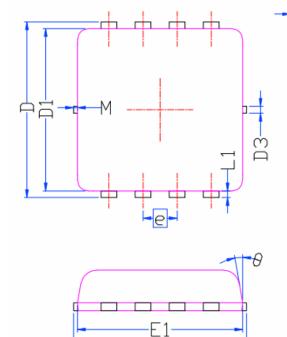


Figure 11 Normalized Maximum Transient Thermal Impedance

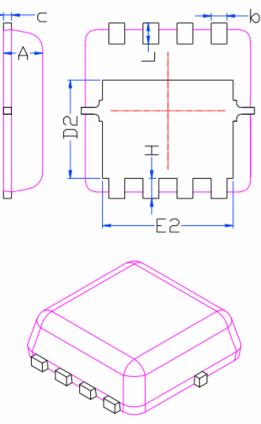


# <u>NCEP3065QU</u>

# DFN3.3X3.3-8L Package Information



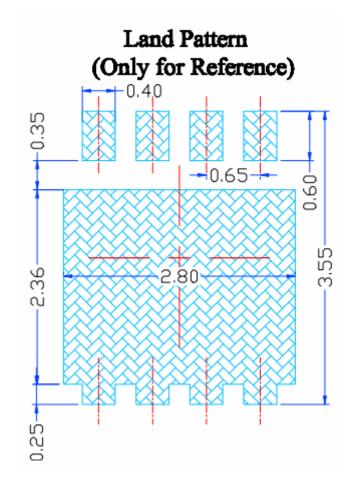
F



2 mm h a l	Dimensions In Millimeters				
Symbol	Min.	Nom.	Max.		
A	0.70	0.75	0.80		
b	0.25	0.30	0.35		
с	0.10	0.15	0.25		
D	3.25	3.35	3.45		
D1	3.00	3.10	3.20		
D2	1.78	1.88	1.98		
D3	-	0.13	-		
E	3.10	3.20	3.30		
E1	3.00	3.15	3.20		
E2	2.39	2.49	2.59		
e		0.65BSC			
Н	0.30	0.39	0.50		
L	0.30	0.40	0.50		
L1	-	0.13	-		
M	*	*	0.15		
θ		10 <sup>°</sup>	12 <sup>°</sup>		

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